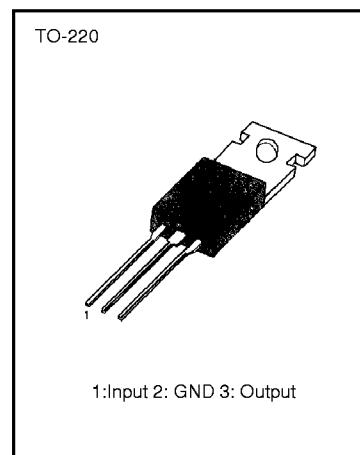


3-TERMINAL 0.5A POSITIVE VOLTAGE REGULATORS

The MC78MXXC/I series of three-terminal positive regulators are available in the TO-220 package with several fixed output voltages making it useful in a wide range of applications.



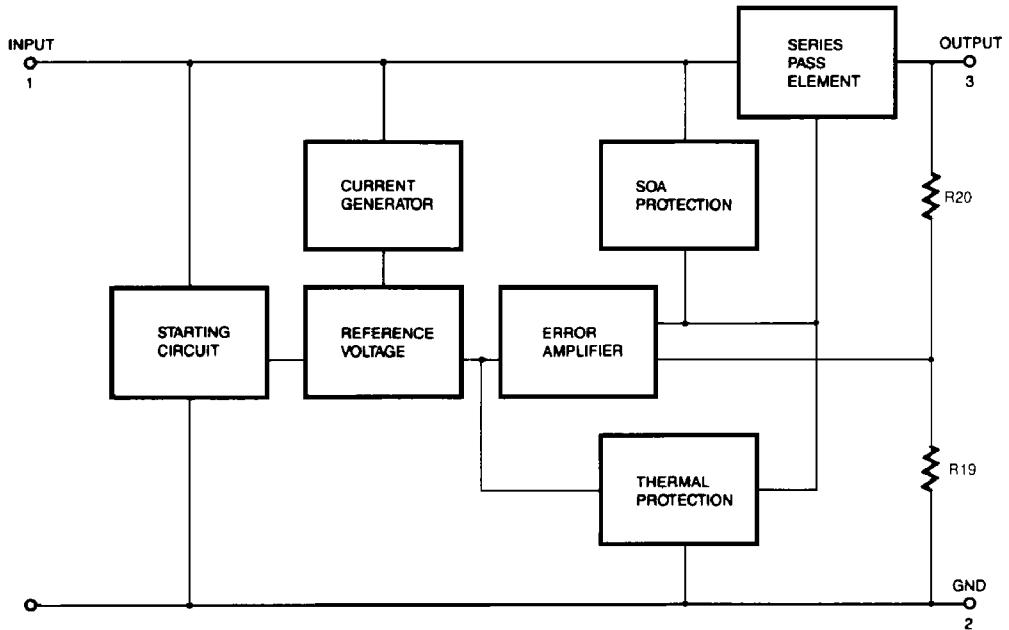
FEATURES

- Output Current up to 0.5A
- Output Voltages of 5; 6; 8; 10; 12; 15; 18; 20; 24V
- Thermal Overload Protection
- Short Circuit Protection
- Output Transistor SOA Protection
- Industrial and commercial temperature range

ORDERING INFORMATION

Device	Package	Operating Temperature
MC78MXXCT	TO-220	0 ~ +125°C
MC78MXXICT	TO-220	- 40 ~ +125°C

BLOCK DIAGRAM



Rev. B

FAIRCHILD
SEMICONDUCTOR™

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ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Input Voltage (for $V_O = 5V$ to $18V$) (for $V_O = 24V$)	V_I	35	V
	V_I	40	V
Thermal Resistance Junction-Cases	R_{EJC}	5	$^{\circ}C / W$
Thermal Resistance Junction-Air	R_{EJA}	65	$^{\circ}C / W$
Operating Temperature Range KA78XXI KA78XX	T_{OPR}	-40 ~ + 125 0 ~ + 125	$^{\circ}C$ $^{\circ}C$
Storage Temperature Range	T_{STG}	-65 ~ + 150	$^{\circ}C$

MC78M05/I ELECTRICAL CHARACTERISTICS(Refer to the test circuits, $T_{MIN} = T_J = 125^{\circ}C$, $I_O = 350mA$, $V_I = 10V$, unless otherwise specified, $C_L = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^{\circ}C$	4.8	5	5.2	V
		$I_O = 5$ to $350mA$ $V_I = 7$ to $20V$	4.75	5	5.25	
Line Regulation	ΔV_O	$I_O = 200mA$	$V_I = 7$ to $25V$		100	mV
		$T_J = 25^{\circ}C$	$V_I = 8$ to $25V$		50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^{\circ}C$			100	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^{\circ}C$			50	
Quiescent Current	I_Q	$T_J = 25^{\circ}C$			4.0	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$			0.5	mA
		$I_O = 200mA$			0.8	
$V_I = 8$ to $25V$						
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$ $T_J = 0$ to $125^{\circ}C$			- 0.5	mV/ $^{\circ}C$
Output Noise Voltage	V_N	$f = 10Hz$ to $100KHz$			40	μV
Ripple Rejection	RR	$f = 120Hz$, $I_O = 300mA$ $V_I = 8$ to $18V$	62			dB
Dropout Voltage	V_D	$T_J = 25^{\circ}C$, $I_O = 500mA$			2	V
Short Circuit Current	I_{SC}	$T_J = 25^{\circ}C$, $V_I = 35V$			300	mA
Peak Current	I_{PK}	$T_J = 25^{\circ}C$			700	mA

* T_{MIN} T_J T_{MAX} MC78MXXI: $T_{MIN} = -40^{\circ}C$, $T_{MAX} = +125^{\circ}C$ MC78MXX: $T_{MIN} = 0^{\circ}C$, $T_{MAX} = +125^{\circ}C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

NC78M06/I ELECTRICAL CHARACTERISTICS

(Refer to the test circuits, $T_{MIN} = 125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = 11\text{V}$, unless otherwise specified, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^{\circ}\text{C}$		5.75	6	6.25	V
		$I_O = 5$ to 350mA	$V_I = 8$ to 21V	5.7	6	6.3	
Line Regulation	ΔV_O	$I_O = 200\text{mA}$	$V_I = 8$ to 25V			100	mV
		$T_J = 25^{\circ}\text{C}$	$V_I = 9$ to 25V			50	
Load Regulation	ΔV_O	$I_O = 5\text{mA}$ to 0.5A , $T_J = 25^{\circ}\text{C}$				120	mV
		$I_O = 5\text{mA}$ to 200mA , $T_J = 25^{\circ}\text{C}$				60	
Quiescent Current	I_Q	$T_J = 25^{\circ}\text{C}$			4.0	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA				0.5	mA
		$I_O = 200\text{mA}$	$V_I = 9$ to 25V			0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5\text{mA}$			-0.5		mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz		45			μV
		$f = 120\text{Hz}$, $I_O = 300\text{mA}$	$V_I = 9$ to 19V	59			
Dropout Voltage	V_D	$T_J = 25^{\circ}\text{C}$, $I_O = 500\text{mA}$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^{\circ}\text{C}$, $V_I = 35\text{V}$		300			mA
Peak Current	I_{PK}	$T_J = 25^{\circ}\text{C}$			700		mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^{\circ}\text{C}$ MC78MXX: $T_{MIN} = 0^{\circ}\text{C}$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M08/I ELECTRICAL CHARACTERISTICS

(Refer to the test circuits, $T_{MIN} = T_J = 125^\circ C$, $I_O = 350mA$, $V_I = 14V$, unless otherwise specified, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		7.7	8	8.3	V
		$I_O = 5$ to $350mA$ $V_I = 10.5$ to $23V$		7.6	8	8.4	
Line Regulation	ΔV_O	$I_O = 200mA$	$V_I = 10.5$ to $25V$			100	mV
		$T_J = 25^\circ C$	$V_I = 11$ to $25V$			50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^\circ C$				160	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^\circ C$				80	
Quiescent Current	I_Q	$T_J = 25^\circ C$			4.0	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$				0.5	mA
		$I_O = 200mA$ $V_I = 10.5$ to $25V$				0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$			- 0.5		$mV/^{\circ}C$
Output Noise Voltage	V_N	$f = 10Hz$ to $100kHz$			52		μV
Ripple Rejection	RR	$f = 120Hz$, $I_O = 300mA$ $V_I = 9$ to $19V$		56			dB
Dropout Voltage	V_D	$T_J = 25^\circ C$, $I_O = 500mA$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^\circ C$, $V_I = 35V$			300		mA
Peak Current	I_{PK}	$T_J = 25^\circ C$			700		mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^\circ C$ MC78MXX: $T_{MIN} = 0^\circ C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M10/I ELECTRICAL CHARACTERISTICS(Refer to the test circuits, $T_{MIN} = T_J = 125^\circ C$, $I_O = 350mA$, $V_I = 17V$, unless otherwise specified, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		9.6	10	10.4	V
		$I_O = 5$ to $350mA$	$V_I = 12.5$ to $25V$	9.5	10	10.5	
Line Regulation	ΔV_O	$I_O = 200mA$	$V_I = 12.5$ to $25V$			100	mV
		$T_J = 25^\circ C$	$V_I = 13$ to $25V$			50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^\circ C$				200	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^\circ C$				100	
Quiescent Current	I_Q	$T_J = 25^\circ C$			4.1	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$				0.5	mA
		$I_O = 200mA$	$V_I = 12.5$ to $25V$			0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$			- 0.5		mV/ $^\circ C$
Output Noise Voltage	V_N	$f = 10Hz$ to $100KHz$			65		μV
Ripple Rejection	RR	$f = 120Hz$, $I_O = 300mA$		55			dB
Dropout Voltage	V_D	$T_J = 25^\circ C$, $I_O = 500mA$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^\circ C$, $V_I = 35V$			300		mA
Peak Current	I_{PK}	$T_J = 25^\circ C$			700		mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^\circ C$ MC78MXX: $T_{MIN} = 0^\circ C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M12/I ELECTRICAL CHARACTERISTICS(Refer to the test circuits, T_{MIN} $T_J = 125^\circ C$, $I_O = 350mA$, $V_I = 19V$, unless otherwise specified, $C_L = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		11.5	12	12.5	V
		$I_O = 5$ to $350mA$ $V_I = 14.5$ to $27V$		11.5	12	12.6	
Lines Regulation	ΔV_O	$I_O = 200mA$	$V_I = 14.5$ to $30V$			100	mV
		$T_J = 25^\circ C$	$V_I = 16$ to $30V$			50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^\circ C$				240	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^\circ C$				120	
Quiescent Current	I_Q	$T_J = 25^\circ C$			4.1	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$				0.5	mA
		$I_O = 200mA$ $V_I = 14.5$ to $30V$				0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$ $T_J = 0$ to $125^\circ C$			- 0.5		mV/°C
Output Noise Voltage	V_N	$f = 10Hz$ to $100KHz$			75		µV
Ripple Rejection	RR	$f = 120Hz$, $I_O = 300mA$ $V_I = 15$ to $25V$		55			dB
Dropout Voltage	V_D	$T_J = 25^\circ C$, $I_O = 500mA$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^\circ C$, $V_I = 35V$			300		mA
Peak Current	I_{PK}	$T_J = 25^\circ C$			700		mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^\circ C$ MC78MXX: $T_{MIN} = 0^\circ C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M15/I ELECTRICAL CHARACTERISTICS(Refer to the test circuits, $T_{MIN} = -40^{\circ}\text{C}$, $T_J = 125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = 23\text{V}$, unless otherwise specified, $C_L = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^{\circ}\text{C}$		14.4	15	15.6	V
		$I_O = 5 \text{ to } 350\text{mA}$	$V_I = 17.5 \text{ to } 30\text{V}$	14.25	15	15.75	
Line Regulation	ΔV_O	$I_O = 200\text{mA}$	$V_I = 17.5 \text{ to } 30\text{V}$			100	mV
		$T_J = 25^{\circ}\text{C}$	$V_I = 20 \text{ to } 30\text{V}$			50	
Load Regulation	ΔV_O	$I_O = 5\text{mA} \text{ to } 0.5\text{A}$	$T_J = 25^{\circ}\text{C}$			300	mV
		$I_O = 5\text{mA} \text{ to } 200\text{mA}$	$T_J = 25^{\circ}\text{C}$			150	
Quiescent Current	I_Q	$T_J = 25^{\circ}\text{C}$		4.1	6		mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA} \text{ to } 350\text{mA}$				0.5	mA
		$I_O = 200\text{mA}$	$V_I = 17.5 \text{ to } 30\text{V}$			0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5\text{mA}$			- 1		mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz} \text{ to } 100\text{KHz}$		100			μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $I_O = 300\text{mA}$	$V_I = 18.5 \text{ to } 28.5\text{V}$	54			dB
Dropout Voltage	V_D	$T_J = 25^{\circ}\text{C}$, $I_O = 500\text{mA}$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^{\circ}\text{C}$, $V_I = 35\text{V}$		300			mA
Peak Current	I_{PK}	$T_J = 25^{\circ}\text{C}$		700			mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^{\circ}\text{C}$ MC78MXX: $T_{MIN} = 0^{\circ}\text{C}$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M18/I ELECTRICAL CHARACTERISTICS(Refer to the test circuits, $T_{MIN} = T_J = 125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = 26\text{V}$, unless otherwise specified, $C_L = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^{\circ}\text{C}$		17.3	18	18.7	V
		$I_O = 5 \text{ to } 350\text{mA}$ $V_I = 20.5 \text{ to } 33\text{V}$		17.1	18	18.9	
Line Regulation	ΔV_O	$I_O = 200\text{mA}$	$V_I = 21 \text{ to } 33\text{V}$			100	mV
		$T_J = 25^{\circ}\text{C}$	$V_I = 24 \text{ to } 33\text{V}$			50	
Load Regulation	ΔV_O	$I_O = 5\text{mA} \text{ to } 0.5\text{A}$, $T_J = 25^{\circ}\text{C}$				360	mV
		$I_O = 5\text{mA} \text{ to } 200\text{mA}$, $T_J = 25^{\circ}\text{C}$				180	
Quiescent Current	I_Q	$T_J = 25^{\circ}\text{C}$		4.2	6		mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA} \text{ to } 350\text{mA}$				0.5	mA
		$I_O = 200\text{mA}$ $V_I = 21 \text{ to } 33\text{V}$				0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5\text{mA}$ $T_J = 0 \text{ to } 125^{\circ}\text{C}$			- 1.1		mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz} \text{ to } 100\text{KHz}$		100			μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $I_O = 300\text{mA}$ $V_I = 22 \text{ to } 32\text{V}$		53			dB
Dropout Voltage	V_D	$T_J = 25^{\circ}\text{C}$, $I_O = 500\text{mA}$		2			V
Short Circuit Current	I_{SC}	$T_J = 25^{\circ}\text{C}$, $V_I = 35\text{V}$		300			mA
Peak Current	I_{PK}	$T_J = 25^{\circ}\text{C}$		700			mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^{\circ}\text{C}$ MC78MXX: $T_{MIN} = 0^{\circ}\text{C}$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M20/I ELECTRICAL CHARACTERISTICS

(Refer to the test circuits, $T_{MIN} = T_J = 125^\circ C$, $I_O = 350mA$, $V_I = 29V$, unless otherwise specified, $C_L = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		19.2	20	20.8	V
		$I_O = 5$ to $350mA$	$V_I = 23$ to $35V$	19	20	21	
Line Regulation	ΔV_O	$I_O = 200mA$	$V_I = 23$ to $35V$			100	mV
		$T_J = 25^\circ C$	$V_I = 24$ to $35V$			50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^\circ C$				400	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^\circ C$				200	
Quiescent Current	I_Q	$T_J = 25^\circ C$		4.2	6		mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$				0.5	mA
		$I_O = 200mA$	$V_I = 23$ to $35V$			0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$			- 1.1		mV/ $^\circ C$
		$T_J = 0$ to $125^\circ C$					
Output Noise Voltage	V_N	$f = 10Hz$ to $100KHz$		110			μV
Ripple Rejection	RR	$f = 120Hz$, $I_O = 300mA$	$V_I = 24$ to $34V$	53			dB
Dropout Voltage	V_D	$T_J = 25^\circ C$, $I_O = 500mA$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^\circ C$, $V_I = 35V$			300		mA
Peak Current	I_{PK}	$T_J = 25^\circ C$			700		mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^\circ C$ MC78MXX: $T_{MIN} = 0^\circ C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

MC78M24/I ELECTRICAL CHARACTERISTICS

(Refer to the test circuits, $T_{MIN} = T_J = 125^\circ C$, $I_O = 350mA$, $V_I = 33V$, unless otherwise specified, $C_L = 0.33\mu F$, $C_O = 0.1\mu F$)

Characteristic	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		23	24	25	V
		$I_O = 5$ to $350mA$	$V_I = 27$ to $38V$	22.8	24	25.2	
Line Regulation	ΔV_O	$I_O = 200mA$	$V_I = 27$ to $38V$			100	mV
		$T_J = 25^\circ C$	$V_I = 28$ to $38V$			50	
Load Regulation	ΔV_O	$I_O = 5mA$ to $0.5A$, $T_J = 25^\circ C$				480	mV
		$I_O = 5mA$ to $200mA$, $T_J = 25^\circ C$				240	
Quiescent Current	I_Q	$T_J = 25^\circ C$		4.2	6		mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$				0.5	mA
		$I_O = 200mA$	$V_I = 27$ to $38V$			0.8	
Output Voltage Drift	$\frac{\Delta V_O}{\Delta T}$	$I_O = 5mA$			- 1.2		mV/ $^\circ C$
Output Noise Voltage	V_N	$f = 10Hz$ to $100KHz$		170			μV
		$f = 120Hz$, $I_O = 300mA$	$V_I = 28$ to $38V$	50			
Dropout Voltage	V_D	$T_J = 25^\circ C$, $I_O = 500mA$			2		V
Short Circuit Current	I_{SC}	$T_J = 25^\circ C$, $V_I = 35V$		300			mA
Peak Current	I_{PK}	$T_J = 25^\circ C$		700			mA

* T_{MIN} MC78MXXI: $T_{MIN} = -40^\circ C$ MC78MXX: $T_{MIN} = 0^\circ C$ * Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

APPLICATION CIRCUIT

Fig. 1 Fixed output regulator

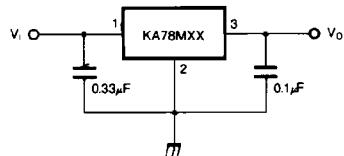
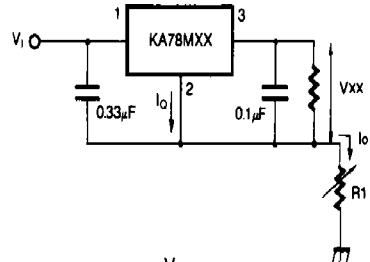


Fig. 2 Constant current regulator



Notes:

- (1) To specify an output voltage, substitute voltage value for "XX".
- (2) Although no output capacitor is needed for stability, it does improve transient response.
- (3) Required if regulator is located an appreciable distance from power Supply filter.

$$I_0 = \frac{V_{XX}}{R_1} + I_0$$

Fig. 4 Adjustable output regulator (7 to 30V)

Fig. 3 Circuit for Increasing output voltage

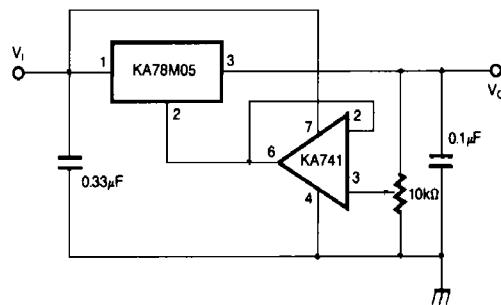
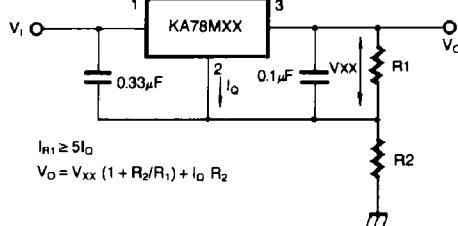
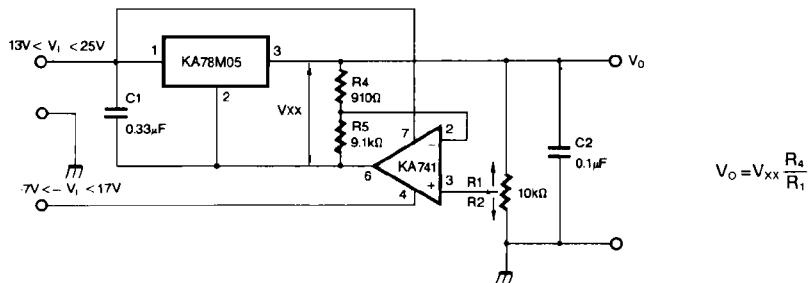


Fig. 5 0.5 to 10V Regulator



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FASTrTM
GTOTM
HiSeCTM

ISOPLANARTM
MICROWIRETM
POPTM
PowerTrenchTM
QSTM
Quiet SeriesTM
SuperSOTTM-3
SuperSOTTM-6
SuperSOTTM-8
TinyLogicTM

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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